Diode Semiconductor Device - Page 1 of 1



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Inclosure M	laterial:
Plastic	
Overall Len	gth:
0.300 inches	
Terminal Le	ength:
1.100 inches	
Overall Dia	neter:
0.140 inches	3
Mounting N	lethod:
Terminal	
Features Pr	ovided:
Hermetically	sealed case
Criticality C	ode Justification:
Feat	
Semicondu	ctor Material:
Silicon	
Voltage Rat	ing In Volts Per Characteristic:
100.0 rever	se voltage, peak
Current Rat	ing Per Characteristic:
30.00 ampe	res forward current, average absolute
Maximum C	perating Tempurature Per Measurement Point:
150.0 degre	es celsius junction
Special Fea	tures:
Item must co	mply with rqmt of desc production standard no. L00835; junction pattern arrangement:
Precious M	aterial And Location:
Terminal su	faces silver
Precious M	aterial:
Silver	
Terminal Ty	pe And Quantity:
2 uninsulate	d wire lead
Shelf Life:	
N/a	
Unit Of Mea	sure:
Demilitariza	ition:
No	
Fiig:	